

30 June 2026

Company Update

4DS Memory Limited (“4DS” or “the Company”) is pleased to provide an update regarding the HGST Joint Development Agreement (“JDA”) and the Indian business development activities.

HGST Joint Development Agreement

4DS intends to meet with HGST during the course of July 2026 to discuss the potential renewal of the JDA between the two companies.

The Company will inform shareholders of the outcome of these discussions as soon as they are completed.

Indian Business Development

The Board is pleased to report that Executive Chairman David McAuliffe has completed a series of productive meetings across India's rapidly developing semiconductor and research ecosystem.

During the visit, the Company engaged with the India Semiconductor Mission (ISM) and senior government officials in Delhi, the Semi-Conductor Laboratory (SCL) in Mohali - India's only operational semiconductor fabrication facility - and leading research institutions including IIT Delhi, IIT Bombay and the Indian Institute of Science (IISc) in Bangalore.

The Company also met with representatives of two of India's largest industrial conglomerates, together with several organisations with access to defence and commercial applications for 4DS's Interface Switching ReRAM technology.

The visit confirmed that 4DS's 60nm ReRAM technology is well aligned with India's current semiconductor manufacturing capability and growth trajectory, and that the Company is engaging with the market at an opportune time as India accelerates investment in domestic semiconductor infrastructure.

In addition to fabrication and commercialisation discussions, the Company explored potential opportunities in neuromorphic computing and Computing-in-Memory (CIM) architectures with several of the institutions visited. The Company has executed non-disclosure agreements with a number of parties and is progressing engagement frameworks to further assess and develop these opportunities.

The Company looks forward to updating shareholders as these discussions advance.



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This announcement has been authorised for release by the Board of 4DS Memory Limited.

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About 4DS

4DS Memory Limited (ASX: 4DS), with facilities located in Silicon Valley, is a semiconductor technology company bringing high bandwidth, high endurance, persistent non-volatile memory to advanced CMOS process nodes. Its technology, known as Interface Switching ReRAM, features tuneable persistence and low energy per bit for today's most challenging compute intensive and AI processor applications. Established in 2007, 4DS owns a patented IP portfolio, comprising 34 USA patents, and is the first company to develop PCMO ReRAM, on an advanced CMOS processing node. For more information, please visit www.4dsmemory.com.